



MBR735 THRU MBR760

7.5 AMPS. Schottky Barrier Rectifiers



Voltage Range
35 to 60 Volts
Current
7.5 Amperes

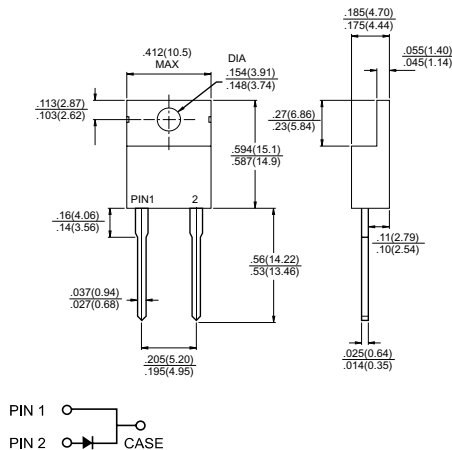
Features

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon rectifier, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guarding for overvoltage protection
- ✧ High temperature soldering guaranteed: 250°C/10 seconds, 0.25"(6.35mm) from case

Mechanical Data

- ✧ Cases: JEDEC TO-220A molded plastic body
- ✧ Terminals: Lead solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams

TO-220A



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	MBR735	MBR745	MBR750	MBR760	Units
Maximum Recurrent Peak Reverse Voltage	35	45	50	60	V
Maximum RMS Voltage	24	31	35	42	V
Maximum DC Blocking Voltage	35	45	50	60	V
Maximum Average Forward Rectified Current See Fig. 1	7.5				A
Peak Repetitive Forward Current (Square Wave, 20KHz) at Tc=105°C	15.0				A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	150				A
Peak Repetitive Reverse Surge Current (Note 1)	1.0		0.5		A
Maximum Instantaneous Forward Voltage at (Note 2) If=7.5A,Tc=25°C If=7.5A,Tc=125°C If=15A,Tc=25°C If=15A,Tc=125°C	- 0.57 0.84 0.72		0.75 0.65 - -		V
Maximum Instantaneous Reverse Current @ Tc =25°C at Rated DC Blocking Voltage (Note 1) @ Tc=125°C	0.1 15.0		0.5 50		mA mA
Voltage Rate of Change (Rated VR)	10,000		10,000		V/μS
Maximum Thermal Resistance, (Note 3) RθJC RθJA	3.0 60.0				°C/W
Operating Junction Temperature Range Tj	-65 to +150				°C
Storage Temperature Range TSTG	-65 to +175				°C

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case and/or Thermal Resistance from Junction to Ambient

RATINGS AND CHARACTERISTIC CURVES (MBR735 THRU MBR760)

FIG.1- FORWARD CURRENT DERATING CURVE

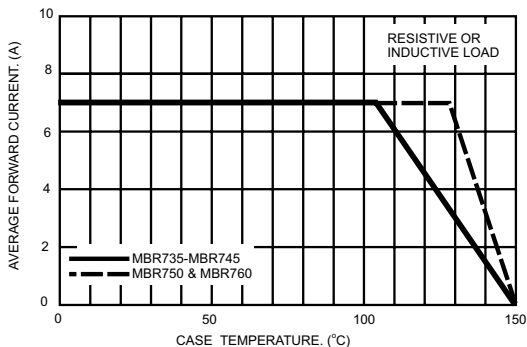


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

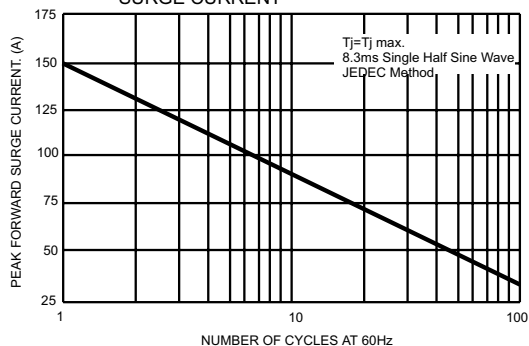


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

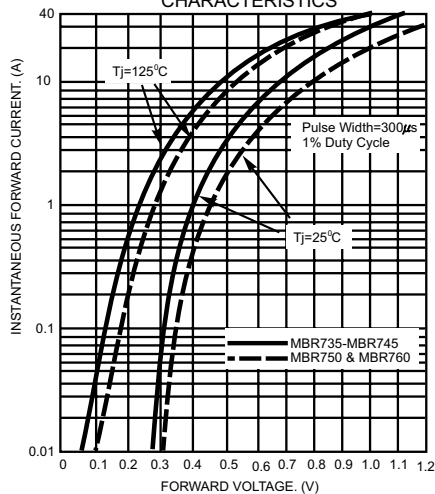


FIG.4- TYPICAL REVERSE CHARACTERISTICS

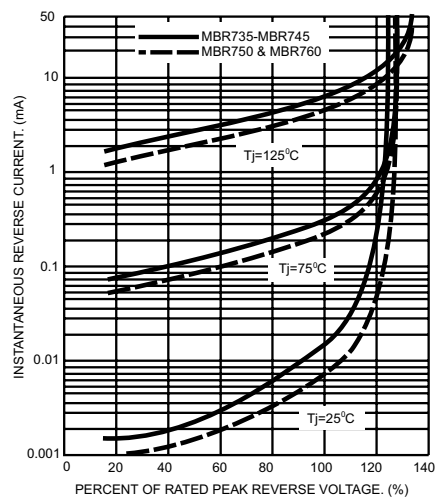


FIG.5- TYPICAL JUNCTION CAPACITANCE

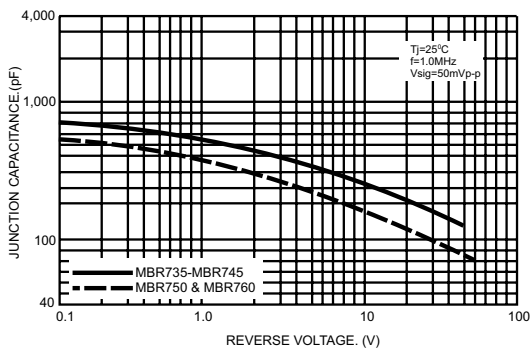


FIG.6- TYPICAL TRANSIENT THERMAL IMPEDANCE

